NSN 5961-01-346-7575

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Inclosure Material:

Metal

Overall Length:

Between 0.170 inches and 0.210 inches

Terminal Length:

Between 0.500 inches and 0.750 inches

Overall Diameter:

Between 0.209 inches and 0.230 inches

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-72

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 drain to source voltage and 50.0 drain to gate voltage

Power Rating Per Characteristic:

300.0 milliwatts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

4 uninsulated wire lead

Specification Data:

81349-mil-s-19500/375 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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